# **MOSPEC**

## S30D100CS

#### **Schottky Barrier Rectifiers**

Using the Schottky Barrier principle with a refractory barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

#### Features

- \*Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \*150°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives



#### **MAXIMUM RATINGS**

Characteristic	Symbol	S30D100CS	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	70	V
Average Rectifier Forward Current ( per diode ) Total Device (Rated $V_{\text{R}})$	I <sub>F(AV)</sub>	15 30	А
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	30	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I <sub>FSM</sub>	275	A
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

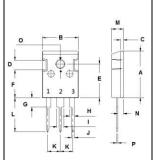
#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 15 \text{ Amp } T_C = 25^{\circ}C$ ) ( $I_F = 15 \text{ Amp } T_C = 125^{\circ}C$ )	V <sub>F</sub>		0.78 0.68	0.85 	v
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^{\circ}C$ ) ( Rated DC Voltage, $T_C = 125^{\circ}C$ )	I <sub>R</sub>		0.09 0.5	200	uA mA



30 AMPERES 100 VOLTS



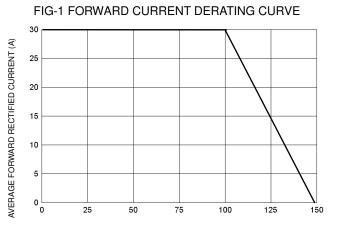


DIM	MILLIMETERS			
DIN	MIN	MAX		
Α	19.80	20.20		
В	15.45	15.75		
С	0.95	1.25		
D	3.85	4.15		
E	14.15	14.45		
F	11.70	12.10		
G	3.80	4.20		
Н	1.80	2.20		
1	2.80	3.20		
J	1.05	1.35		
K	5.26	5.66		
L	13.90	14.50		
Μ	4.60	5.00		
N	2.35	2.65		
0	3.40	3.80		
Р	0.38	0.62		

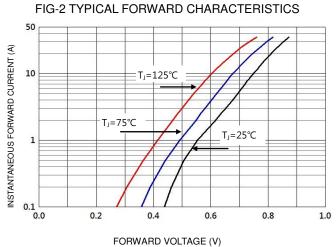


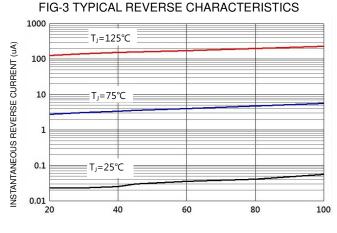


### S30D100CS



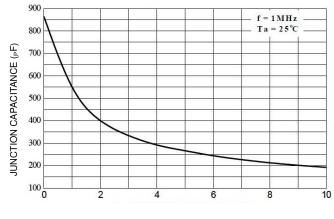
CASE TEMPERATURE (℃)





PERCENT OF RATED PEAK REVERSE VOLTAGE (V)

FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (V)

300 PEAK FORWARD SURGE CURRENT (Amp.) 250 200 150 100 50

NUMBER OF CYCLES AT 60 Hz

10

100

FIG-5 PEAK FORWARD SURGE CURRENT

0 L 1



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